

Electronic Acknowledgement Receipt

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International Application Number:	
Confirmation Number:	7331
Title of Invention:	Solution-based fabrication of photovoltaic cell
First Named Inventor/Applicant Name:	Dong Yu
Customer Number:	27652
Filer:	Hao Y. Tung
Filer Authorized By:	
Attorney Docket Number:	NSL-029
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Application Type:	Utility under 35 USC 111(a)

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Submitted with Payment	yes
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RAM confirmation Number	4539
Deposit Account	
Authorized User	

File Listing:

Document Number	Document Description	File Name	File Size(Bytes) /Message Digest	Multi Part /.zip	Pages (if appl.)
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1	Information Disclosure Statement (IDS) Filed	NSL-029_IDS_040208.pdf	128469	no	7
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Total Files Size (in bytes):			35274152		
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